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PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM	FILING DATE	CLASS	SUBCLASS	GAU	EXAMINER
10028643	12/20/2001	438	216	2714 2812	L. PHAM

**APPLICANTS: Ahn Kie; Forbes Leonard;

**CONTINUING DATA VERIFIED:

** FOREIGN APPLICATIONS VERIFIED:

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	
Foreign priority claimed	<input type="checkbox"/> yes <input type="checkbox"/> no	ATTORNEY DOCKET NO	
35 USC 119 conditions met	<input type="checkbox"/> yes <input type="checkbox"/> no		1303.030US1
Verified and Acknowledged Examiner's initials			
TITLE : Low-temperature grown high quality ultra-thin CoTiO ₃ gate dielectrics			
U.S. DEPT. OF COMM./PAT. & TM-PTO-436L(Rev. 12-94)			